SG6849



Low-Power Green-Mode PWM Flyback Power Controller without Secondary Feedback

FEATURES

- Linearly decreasing PWM frequency
- Green-mode under light-load and zero-load conditions
- Constant voltage (CV) and constant current (CC)
- No secondary feedback
- Low startup current (5uA)
- Low operating current (3.6mA)
- Leading-edge blanking
- Constant power limit
- Universal AC input range
- Synchronized slope compensation
- 150°C OTP sensor with hysteresis
- V_{DD} over voltage clamping
- Cycle-by-cycle current limiting
- Under voltage lockout (UVLO)
- Fixed PWM frequency (65kHz)
- Gate output maximum voltage clamped at 16.7V
- Small SOT-26 package

APPLICATIONS

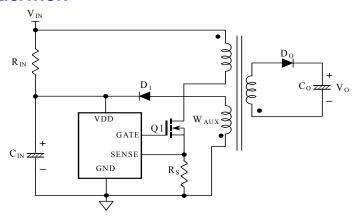
Low-power flyback power converters, such as

- Battery chargers for cellular phones, cordless phones, PDAs, digital cameras, and power tools.
- Power adapters for ink jet printers, video game consoles, and portable audio players.
- Open-frame SMPS for TV/DVD standby and other auxiliary supplies, home appliances, consumer electronics, and PC 5V standby-power.
- Replacements for linear transformers and RCC SMPS.

DESCRIPTION

This highly integrated PWM controller provides several features to enhance the performance of low power flyback converters. To minimize standby power consumption, the proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load and zero-load conditions. green-mode function enables the power supply to easily meet international power conservation requirements. The supply voltage V_{DD} is also used for feedback compensation, to regulate the output voltage without requiring a conventional TL431 and a photo-coupler. Another advantage of the SG6849 is that the typical startup current is only 5uA, while the typical operating current can be as low as 3.6mA. A large startup resistance could be used to achieve even higher power conversion efficiency. Built-in synchronized slope compensation maintains the stability of peak current-mode control. Proprietary internal compensation ensures constant output power limiting over a universal range of AC input voltages, from 90VAC to 264VAC. The SG6849 provides many protection functions. Pulse-by-pulse current limiting ensures a constant output current, even if a short circuit occurs. Also, the internal protection circuit will disable PWM output, if V_{DD} exceeds 22.7V. The gate output is clamped at 16.7V to protect the power MOS from over-voltage damage. The built-in over temperature protection (OTP) function will shutdown the controller at 150°C with a 20°C hysteresis. The SG6849 is designed to provide a low-cost total solution for flyback converters. It is available in a small footprint, 6-pin, SOT-26 package.

TYPICAL IC APPLICATION





MARKING INFORMATION

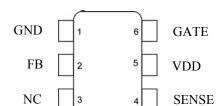
MXYWW O

M: Mask Version
X: B= SG6849-65T

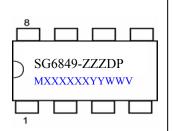
: Lead Free

Y: Year

WW: Work Week



PIN CONFIGURATION



ZZZ: 65

D: D=DIP

P: Z = Lead free

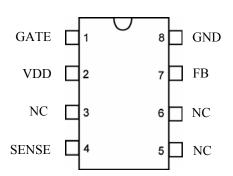
Null=Regular package

M: Mask Version

XXXXXX: Wafer Lot

YY: Year WW: Week

V: Assembly Location



ORDERING INFORMATION

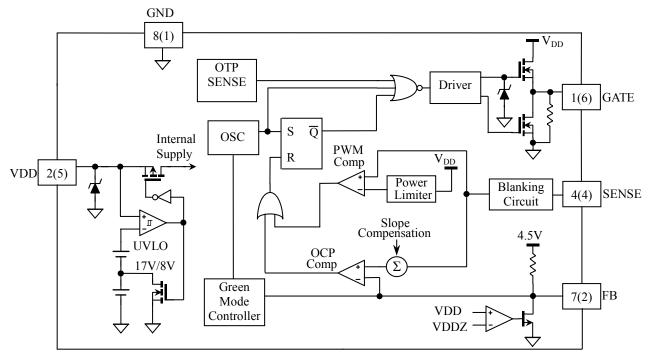
Part Number	PWM Frequency	Package
SG6849-65T	65kHz	6-Pin SOT-26
SG6849-65D	65kHz	8-pin DIP-8
SG6849-65TZ	65kHz	6-Pin SOT-26 (Lead Free)
SG6849-65DZ	65kHz	8-pin DIP-8 (Lead Free)

PIN DESCRIPTIONS

Name	Pin No.		Type	Junation			
Name	DIP-8	SOT-26	Туре	Function			
GATE	1	6	Driver Output	The totem-pole output driver to drive the power MOSFET.			
VDD	2	5	Supply	Power supply.			
NC	3	NA		NC pin.			
				Current sense. It senses the voltage across a sensed resistor. To provide over-current			
SENSE	4	4	Analog Input	protection, PWM output is disabled if the voltage exceeds an internal threshold. This pin			
				also provides current information for current-mode control.			
NC	5	3		NC pin.			
NC	6	NA		NC pin.			
				Feedback. The FB pin provides feedback information to the internal PWM comparator.			
FB	7	2	Analog Input	This feedback is used to control the duty cycle. When no feedback is provided, this pin is			
				left open.			
GND	8	1	Supply	Ground.			



BLOCK DIAGRAM



DIP-8(SOT-26)

SG6849

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Value		
	DC Supply Voltage*	25		V	
V_{VDD}	Zener Clamp	30		V	
	Zener Current	10		mA	
V_{FB}	FB Pin Input Voltage	-0.3 to 7		V	
V _{SENSE}	Sense Pin Input Voltage	-0.3 to 7		V	
0	Device Dissipation (T =05°C)	SOT-26	247		
P_D	Power Dissipation (T _A =85°C)	DIP-8	478	mW	
D	Thermal Resistance (Junction to Air)**	SOT-26	263.3	°C/W	
$R_{\theta j-a}$	Thermal Resistance (Junction to Air)	DIP-8	135.7	C/VV	
D	Thermal Resistance (Junction to Case)**	SOT-26	119.6	°C/W	
$R_{\theta j-c}$	Thermal Resistance (Junction to Case)	DIP-8	67.1	C/VV	
$T_{\rm J}$	Operating Junction Temperature	-40 to 125		°C	
T_{STG}	Storage Temperature Range	-55 to +150		°C	
TL	Lead Temperature (Wave soldering or IR, 10 seconds)	260		°C	
	ESD Capability, Human Body Model	3		KV	
	ESD Capability, Machine Model	300		V	

^{*} All voltage values, except differential voltages, are given with respect to the network ground terminal.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit	
V_{DD}	DC Supply Voltage	with Secondary Feedback	<20	V
		without Secondary Feedback	<22.7	V
T _A	Operating Ambient Temperature		-20 to +85	°C

ELECTRICAL CHARACTERISTICS (V_{DD} = 15V, T_A = 25°C, unless noted)

Feedback Input Section

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
I _{FB-ZDC}	Zero Duty-Cycle FB Input Current			1.15	1.4	mA
$V_{\text{FB-OPEN}}$	Open Loop Voltage		4.5			V
Z_{FB}	Input Impedance	I _{FB} =0.1mA to 0.2mA		2.4		ΚΩ
$V_{\text{DD-FB}}$	V	FB is Open	20	22.7	25	V
	V _{DD} Feedback Threshold Voltage*	I _{FB} =0.4mA	18	20	22	V

^{*}The feedback input is pulled by a transistor that is controlled by the V_{DD} signal while $V_{DD} \ge V_{DDZ}$.

^{*} Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device.

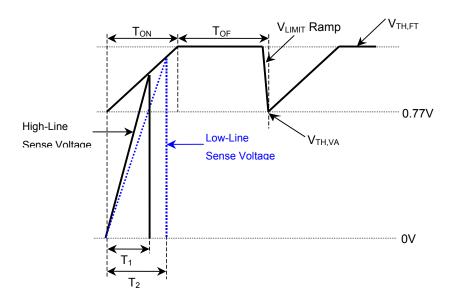
^{**} Thermal JA test board size: SOT 18×12×1.6mm/FR4; DIP 40×35×1.6mm/FR4

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Current Sense Section

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
t _{PD}	Propagation Delay			100		ns
	Current Limiting Valley Threshold Voltage	V _{DD} =20V	0.84	0.89	0.94	V
V_{STHVA}		V _{DD} =15V	0.72	0.77	0.82	V
		V _{DD} =10V	0.58	0.63	0.68	V

^{*} For proper operation



Oscillator Section

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Fosc	Frequency in nominal mode		60	65	70	KHz
F _{OSC-G}	Green-Mode Frequency		20	25	30	KHz
I _{FB-G}	Green-Mode Ending FB Current		0.9	1.15	1.4	mA
F_{DV}	Frequency Variation versus V _{DD} Deviation	V _{DD} =10 to 20V			2	%
V	V _{DD} -Low Threshold Voltage for Exiting		V_{DD}	V_{DD}	V_{DD}	V
$V_{DD-TH-G}$	Green-Mode OFF		OFF+1.0	OFF+1.5	OFF+2.0	V

Output Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
DCY _{MAX}	Maximum Duty Cycle		70	75	80	%
t _{LEB} Leading Edge Blanking Time				310		ns
V_{GATE-L}	Output Voltage Low	V _{DD} =15V, I _O =10mA			1.5	V
$V_{\text{GATE-H}}$	Output Voltage High	V _{DD} =15V, I _O =-10mA	8			V
tr	Rising Time	V _{DD} =15V, C _L =1nF		200		ns
tf	Falling Time	V_{DD} =15V, C_L =1nF		80		ns
$V_{GATE\text{-}CLAMP}$	Output Clamp Voltage	V _{DD} =20V		16.7	18	V



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Over Temperature Protection (OTP)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Temp- _{OTP}	Protection Junction Temperature*1			150		°C
Temp-Restart	Restart Junction Temperature*2			130		°C

^{*1}When activated, the output is disabled and the latch is turned off.

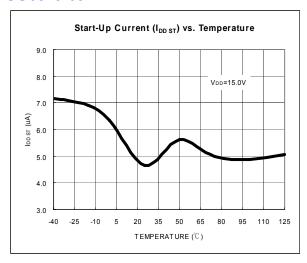
VDD Section

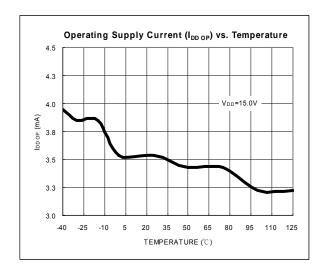
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V _{DD ON} Turn-On Threshold Voltage			16	17	18	V
V _{DD OFF} Turn-Off Threshold Voltage			7.5	8	8.5	V
I _{DD ST}	Startup Current	V _{DD} =15V		5	20	uA
I _{DD OP} Operating Supply Current		V_{DD} =15 V C_L =1nF		3.6	4.6	mA
$V_{DD\ CLAMP}$	Zener Diode Breakdown Voltage	I _{DD} =10mA		28	30	V

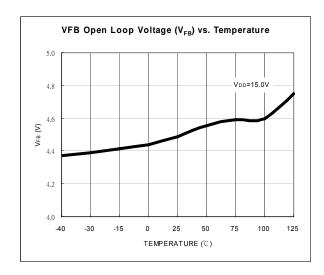
² This is the threshold temperature for enabling the output again and resetting the latch, after over temperature protection has been activated.

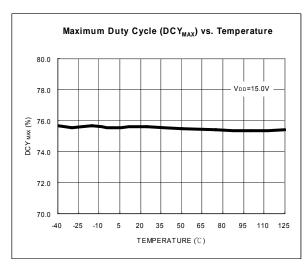


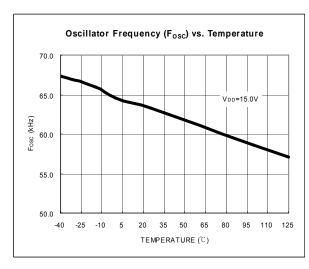
TYPICAL CHARACTERISTICS SG6849-65

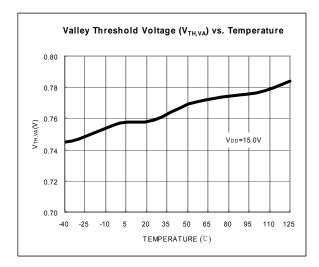






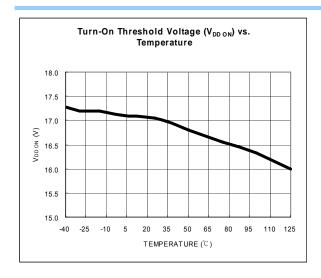


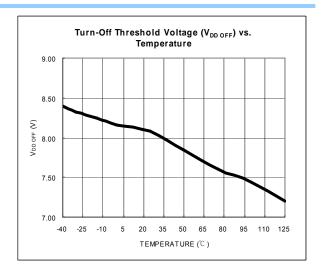


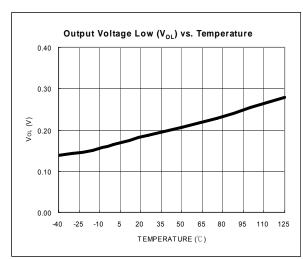


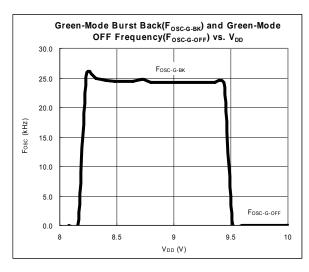


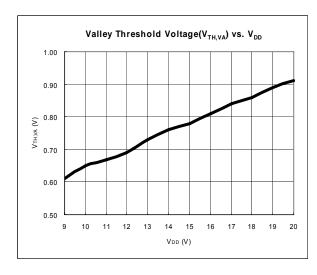
SG6849

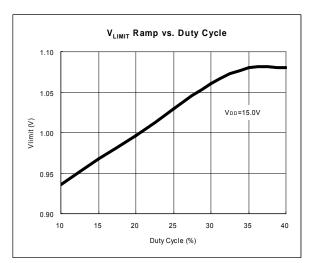




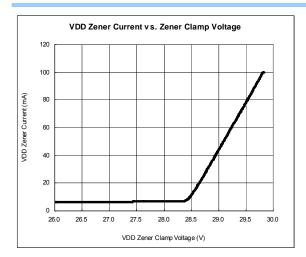








SG6849





OPERATION DESCRIPTION

SG6849 devices integrate many useful functions for low power switch mode power supplies. The following descriptions highlight the key features of the SG6849.

Startup Current

The required startup current is only 5uA. This allows a high-resistance, low-wattage startup resistor to be used to supply the controller's startup power. A 1.5 M Ω /0.25W startup resistor can be used over a wide input range (100V-240V AC) with very little power loss.

Operating Current

The operating current is normally 3.6mA. The low operating current results in higher efficiency and reduces the required $V_{\rm DD}$ hold-up capacitance. A $10 {\rm uF}/25 {\rm V}$ $V_{\rm DD}$ hold-up capacitor can be used over a wide input range (100V-240V AC) with very little power loss.

Green Mode Operation

The proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency under light-load and zero-load conditions. The on-time is limited to provide better protection against brownouts and other abnormal conditions.

This green-mode function dramatically reduces power consumption under light-load and zero-load conditions. Power supplies using the SG6849 can easily meet international restrictions regarding standby power-consumption.

Constant Voltage (CV) and Constant Current (CC) without Feedback

The SG6849 can tightly regulate the output voltage and provide over current protection without requiring secondary-side feedback signals. For improved CV and CC accuracy, the transformer leakage inductance should be reduced as much as possible.

Over Temperature Protection (OTP)

The SG6849 has a built-in temperature sensing circuit to shut down PWM output once the junction temperature exceeds 150°C. While PWM output is shut down, the V_{DD} voltage will gradually drop to the UVLO voltage. Some of the SG6849's internal circuits will be shut down, and V_{DD} will gradually start increasing again. When V_{DD} reaches 17V, all the internal circuits, including the temperature sensing circuit, will start operating normally. If the junction temperature is still higher than 150°C, the PWM controller will be shut down immediately. This situation will continue until the temperature drops below 130°C. The PWM output will then be turned back on. The temperature hysteresis window for the OTP circuit is 20°C.

V_{DD} Over Voltage Clamping

 V_{DD} over voltage clamping is built in to prevent damage from over-voltage conditions. When V_{DD} exceeds 22.7V, PWM output is shut down. Over-voltage conditions may be caused by an open photo-coupler loop or a short circuit in the output.

Oscillator Operation

The oscillation frequency is fixed at 65kHz for the SG6849-65.

Leading Edge Blanking

Each time the power MOSFET is switched on, a turn-on spike will inevitably occur at the sense-resistor. To avoid premature termination of the switching pulse, a 310ns leading-edge blanking time is built in. Conventional RC filtering is not necessary. During this blanking period, the current-limit comparator is disabled, and it cannot switch off the gate drive.

Constant Output Power Limit

When the SENSE voltage across the sense resistor R_S reaches the threshold voltage (around 1.0V), the output GATE drive will be turned off following a small propagation delay T_{PD} . This propagation delay will



introduce an additional current proportional to $T_{PD}*V_{IN}/L_P$. The propagation delay is nearly constant regardless of the input line voltage V_{IN} . Higher input line voltages will result in larger additional currents. Thus, under high input-line voltages the output power limit will be higher than under low input-line voltages.

Over a wide range of AC input voltages, the variation can be significant. To compensate for this, the threshold voltage is adjusted by adding a positive ramp (Vlimit ramp). This ramp signal can vary from 0.77V to 1.05V for SG6849-65, and it flattens out at 1.05V. A smaller threshold voltage forces the output GATE drive to terminate earlier, thus reducing total PWM turn-on time and making the output power equal to that of the low line input. This proprietary internal compensation feature ensures a constant output power limit over a wide range of AC input voltages (90VAC to 264VAC).

Under Voltage Lockout (UVLO)

The turn-on/turn-off thresholds of the SG6849 are fixed internally at 17V/8V. To enable the SG6849 during startup, the hold-up capacitor must first be charged to 17V through the startup resistor.

The hold-up capacitor will continue to supply V_{DD} before energy can be delivered from the auxiliary winding of the main transformer. V_{DD} must not drop below 8V during this startup process. This UVLO hysteresis window ensures that the hold-up capacitor can adequately supply V_{DD} during startup.

Gate Output

The SG6849 BiCMOS output stage is a fast totem pole gate driver. Cross-conduction has been avoided to minimize heat dissipation, increase efficiency, and enhance reliability. The output driver is clamped by an internal 16.7V Zener diode in order to protect the power MOSFET transistors against any harmful over-voltage gate signals.

Slope Compensation

The sensed voltage across the current sense resistor is used for current mode control and pulse-by-pulse current limiting. The built-in slope compensation function improves power supply stability. Furthermore, it prevents sub-harmonic oscillations that normally would occur because of peak current mode control. A positively sloped, synchronized ramp is activated by the SG6849 with every switching cycle. The slope of the ramp is

 $\frac{0.33 \times Duty}{Duty(\text{max})}$

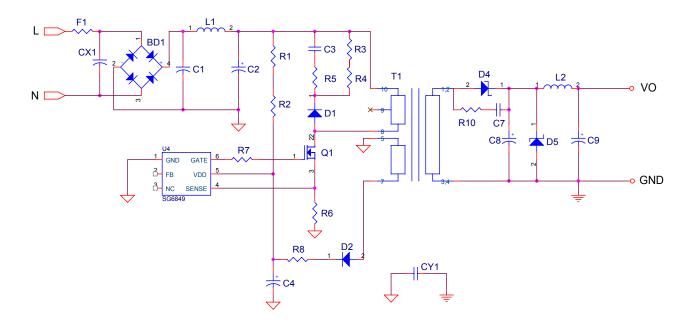
Noise Immunity

Noise from the current sense or the control signal may cause significant pulse width jitter, particularly in continuous-conduction mode. Slope compensation helps alleviate this problem. Good placement and layout practices should be followed. The designer should avoid long PCB traces and component leads. Compensation and filter components should be located near the SG6849. Finally, increasing the power-MOS gate resistance is advised.



REFERENCE CIRCUIT

3W Flyback 5V/0.6A Circuit, without Secondary-Side Feedback

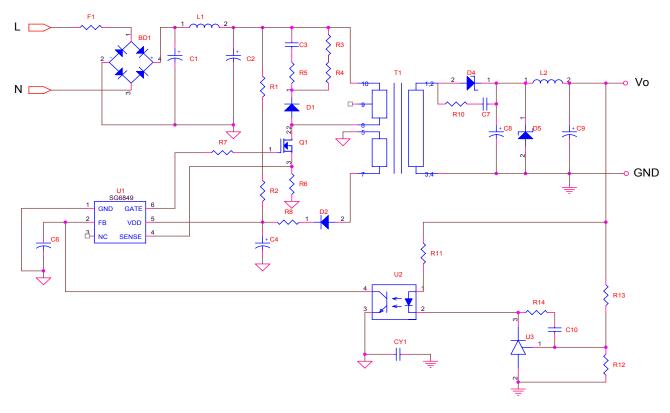


BOM

Sym	bol	Component	Symbol	Component
BD1	(Reference only)	BD DI106 1A/600V	F1	R 1Ω/0.5W
CX1	(Option)	YC 472pF/400V (Y1)	L1	Inductor 20mH 6*8mm
CY1	(Option)	YC 102pF/400V (Y1)	L2	Inductor 10uH 6mm
C1		CC 0.01uF/500V	Q1	MOSFET 1A/600V
C2		EC 10uF/400V 105°C	R1,R2	R 750kΩ/1206
C3		CC 1000pF/500V	R3,R4	R 47kΩ/1206
C4		EC 10uF/50V	R5	R 47Ω/1206
C7	(Option)	CC 102pF/100V 1206	R6	R 4.7Ω/0.5W
C8		EC 470uF/10V 105°C	R7	R 100Ω/0805
C9		EC 220uF/10V 105°C	R8	R 10Ω/1206
D1		Diode FRI07	R10 (Option)	R 10Ω/1206
D2		Diode FR102	T1	Transformer EE-16
D4		Diode SB360	U4	IC SG6849 (Green PWM IC)
D5	(Option)	ZD 6.8V/0.5W		



3W Flyback 5V/0.6A Circuit, with Secondary-Side Feedback

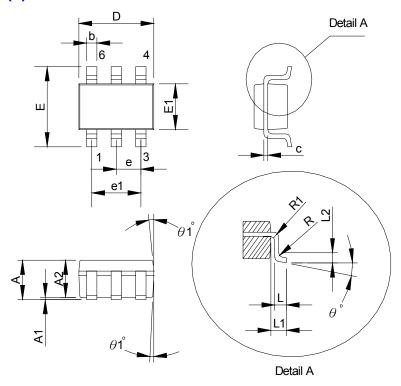


BOM

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Sym	bol	Component	Symbol	Component
BD1	(Reference only)	BD DI106 1A/600V	L2	Inductor 10uH 6mm
CY1	(Option)	YC 102p/400V	Q1	MOSFET 1A/600V
C1		CC 0.01uF/500V	R1,R2	R 750kΩ/1206
C2		EC 10uF/400V 105°C	R4,R3	R 47kΩ/1206
C3		CC 1000p/500V	R5	R 47Ω/1206
C4		EC 10u/50V	R6	R 4.7Ω/0.5W
C6		CC 472p/0805	R7	R 100Ω/0805
C7		CC 102p/100V 1206	R10	R 10Ω/1206
C8		EC 470u/10V 105°C	R8	R 10Ω/1206
C9		EC 470u/10V 105°C	R11	R 100Ω/ 1/8W
C10		CC 222p/0805	R12	R 33kΩ/0805
D1		Diode FR107	R13	R 33kΩ/ 1/8W
D2		Diode FR102	R14	R 4.7kΩ/0805
D4		Diode SB360	T1	Transformer EE-16
D5	(Option)	ZD 6.8V/0.5W	U1	IC SG6849 (Green PWM IC)
F1		R 1Ω/0.5W Resistor	U2	IC PC817
L1		Inductor 20mH 6*8mm	U3	IC TL431



PACKAGE INFORMATION 6 PINS – SOT (T)

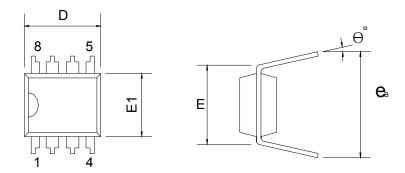


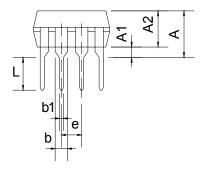
Dimensions:

Symbol	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Typ.	Max.
A			1.45			0.057
A1			0.15			0.006
A2	0.90	1.15	1.30	0.036	0.045	0.051
b	0.30		0.50	0.011		0.020
С	0.08		0.22	0.003		0.009
D		2.90			0.114	
E		2.80			0.110	
E1		1.60			0.063	
е		0.95			0.037	
e1		1.90			0.075	
<u>L</u>	0.30	0.45	0.60	0.020	0.018	0.24
L1		0.60			0.024	
L2		0.25			0.010	
R	0.10			0.004		
R1	0.10		0.25	0.004		0.25
θ°	0°	4°	8°	0°	4°	8°
θ1°	5°	10°	15°	5°	10°	15°



8 PINS - DIP (D)





Dimensions:

Symbol	Millimeter			Inch			
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Α			5.334			0.210	
A1	0.381			0.015			
A2	3.175	3.302	3.429	0.125	0.130	0.135	
b		1.524			0.060		
b1		0.457			0.018		
D	9.017	9.271	10.160	0.355	0.365	0.400	
E		7.620			0.300		
E1	6.223	6.350	6.477	0.245	0.250	0.255	
е		2.540			0.100		
L	2.921	3.302	3.810	0.115	0.130	0.150	
e_B	8.509	9.017	9.525	0.335	0.355	0.375	
θ°	0	7	15	0	7	15	



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LIFE SUPPORT

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